

Investigation of Electrical and Gas Sensing Properties of CeO₂ Nanoparticle Synthesized by Precipitation Method

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Abstract:

In the present research work, pure CeO₂ nanoparticles (NPs) were successfully synthesized using the precipitation method with cerium (III) nitrate hexahydrate [Ce(NO₃)₃·6H₂O] as a precursor. The synthesized CeO₂ NPs were employed to fabricate thick films via the standard screen-printing technique, and their electrical as well as gas sensing properties were systematically studied. The prepared CeO₂ thick films exhibited a resistivity of 5939.03 Ω/m with a negative temperature coefficient of resistance (TCR) value of -0.002815 /°C, confirming their semiconducting behavior. The activation energy values were found to be 0.0546 eV in the low-temperature region (LTR) and 0.2421 eV in the high-temperature region (HTR). Gas sensing analysis revealed that the CeO₂ NPs thick films showed maximum response toward NH₃ gas, with a sensitivity of 76.95% at 120 °C for 1000 ppm concentration, along with fast response and recovery times. These results suggest that CeO₂ NPs thick films are promising candidates for efficient and selective NH₃ gas sensing applications.

Keywords- Hexahydrate, NH₃ gas, sensitivity, electrical, Gas sensing, response time.

1. INTRODUCTION:

The need for gas sensors has become increasingly important due to the rising concerns of environmental pollution, industrial safety, and human health [1]. Harmful and toxic gases such as CO, NH₃, NO₂, SO₂, CH₄, and volatile organic compounds are frequently released from industrial processes, vehicles, and domestic activities, posing serious risks to living beings and the environment even at low concentrations [1, 2]. Gas sensors provide an effective solution for real-time monitoring and detection of these hazardous gases, enabling timely preventive actions [3]. They play a vital role in industries for process control, leak detection, and ensuring workplace safety, as well as in medical diagnostics, smart homes, and environmental monitoring systems. The development of highly sensitive, selective, stable, and low-cost gas sensors is therefore essential for improving air quality management, reducing health hazards, and supporting the advancement of smart and sustainable technologies. Metal oxide-based gas sensors are among the most widely studied and commercially used gas-sensing materials due to their simple fabrication, low cost, high sensitivity, and ability to detect a wide range of toxic and combustible gases [3, 4]. These sensors typically work on the principle of change in electrical resistance when exposed to target gas molecules, which interact with the adsorbed oxygen species on the metal oxide surface. Commonly used metal oxides such as SnO₂, ZnO, TiO₂, WO₃, In₂O₃, and CeO₂ exhibit excellent semiconducting behavior, making them highly effective for gas detection. Their sensing performance strongly depends on factors such as surface area, porosity, particle size, morphology, and the operating temperature [4, 5].

Cerium oxide (CeO_2) nanoparticles also known as nanoceria, possess unique physicochemical properties such as a high oxygen storage capacity, reversible $\text{Ce}^{3+}/\text{Ce}^{4+}$ redox behavior, excellent thermal stability, and strong catalytic activity [6, 7]. Their nanoscale dimensions provide a large surface area, high surface energy, and abundant oxygen vacancies, which enhance their reactivity and make them suitable for multifunctional applications. CeO_2 nanoparticles can be synthesized by various chemical and physical methods, including sol-gel, co-precipitation, hydrothermal, solvothermal, combustion, and green synthesis approaches, each method influencing the particle size, morphology, and defect structure. These synthesis routes allow fine control over crystallinity and surface chemistry, which are crucial for tailoring their performance in different fields [8, 9]. Owing to their remarkable redox and surface properties, CeO_2 nanoparticles find wide applications in catalysis, fuel cells, oxygen sensors, UV-blocking materials, and biomedical fields such as antioxidant, anti-inflammatory, and drug delivery agents [10, 11]. They are extensively explored in gas sensing, photocatalysis, energy storage devices, and environmental remediation due to their strong interaction with gases and pollutants. The versatile physicochemical properties of CeO_2 nanoparticles make them highly attractive for diverse scientific and technological applications [11, 12].

The main aim of the present research work is to synthesize pure CeO_2 nanoparticles (NPs) using the precipitation method with cerium (III) nitrate hexahydrate as a precursor, and to fabricate thick films through the standard screen-printing technique for investigating their electrical and gas sensing properties. The study is focused on evaluating key electrical parameters such as resistivity, temperature coefficient of resistance (TCR), and activation energy, as well as systematically analyzing the gas sensing performance of the prepared CeO_2 thick films toward different gases. Special emphasis is given to examining the sensitivity, selectivity, response and recovery times of the films for NH_3 detection, in order to establish CeO_2 NPs as potential candidates for efficient, selective, and reliable gas sensing applications.

2. EXPERIMENTAL WORK:

2.1 Synthesis of CeO_2 nanoparticles using precipitation method:

Cerium nitrate hexahydrate [$\text{Ce}(\text{NO}_3)_3 \cdot 6\text{H}_2\text{O}$] with 99.99% purity was employed as the precursor material for the synthesis of CeO_2 nanoparticles. Ammonia solution (NaOH) was used as the precipitating agent during the synthesis process to control the pH and facilitate the formation of cerium hydroxide, which upon calcination converted into CeO_2 nanoparticles. The synthesis was carried out using the precipitation method, which is simple, cost-effective, and suitable for obtaining highly pure nanoparticles. The graphical representation of the experimental workflow for the synthesis of CeO_2 nanoparticles via the precipitation route is illustrated in Figure 1 [13-15].

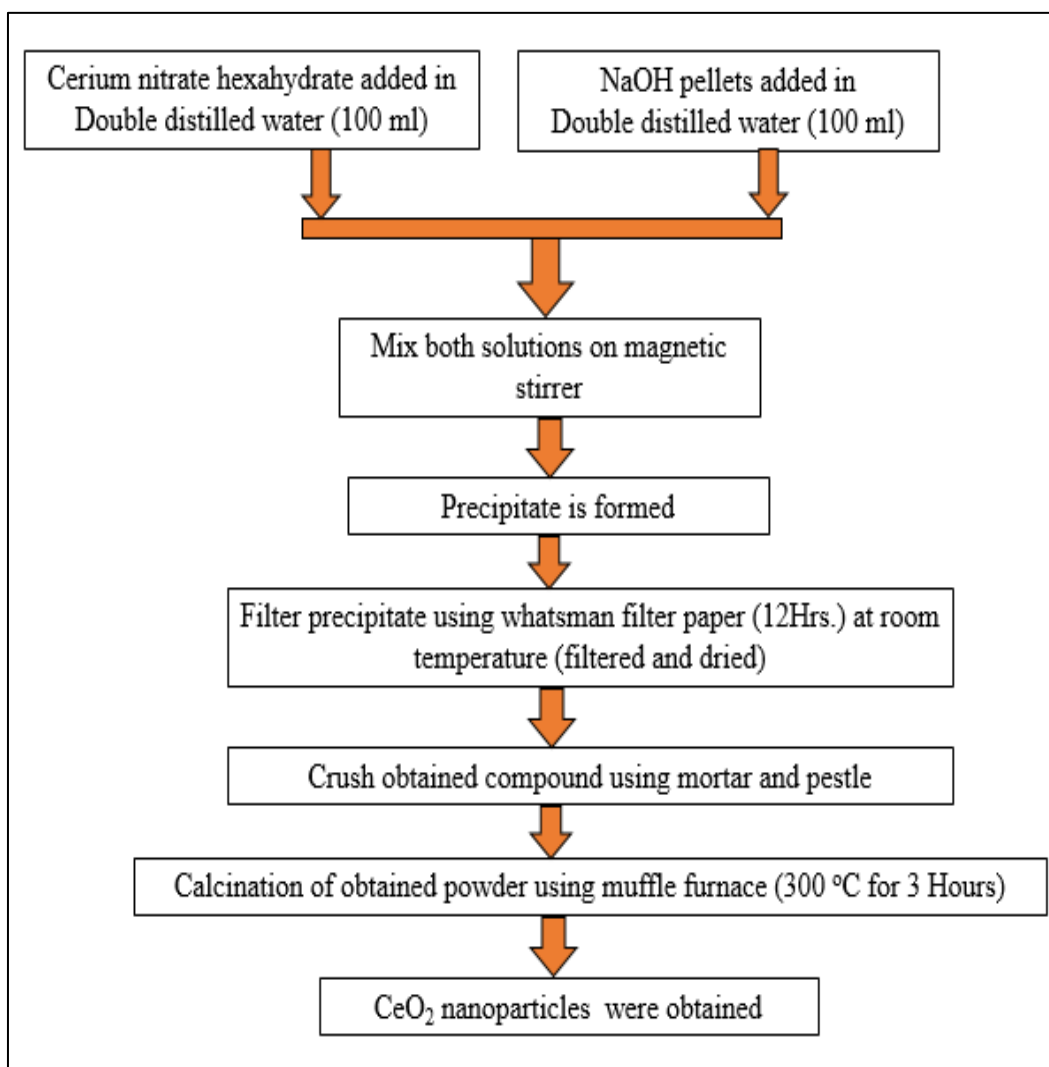


Figure 1: Synthesis steps of CeO₂ nanoparticles using precipitation method

2.2 Preparation of CeO₂ thick films using screen printing technique

The thick films of pure CeO₂ nanoparticles were prepared using the standard screen-printing technique. Initially, the synthesized CeO₂ nanopowder was mixed with an organic binders (BCA & EC) and inorganic (CeO₂ nanopowder) material to form a thixotropic paste of suitable viscosity [16]. This paste was then uniformly deposited onto pre-cleaned glass substrates using a stainless steel mesh screen, ensuring controlled thickness and uniform coating. After printing, the films were dried to remove the organic content and subsequently annealed at 200°C temperature for 2 h to improve adhesion, crystallinity, and surface morphology. The screen-printing process offers advantages such as simplicity, reproducibility, large-area deposition, and precise control over film thickness, making it highly suitable for gas sensor fabrication [16, 17]. The complete procedure for the preparation of CeO₂ thick films using the screen-printing method is schematically illustrated in Figure 2.

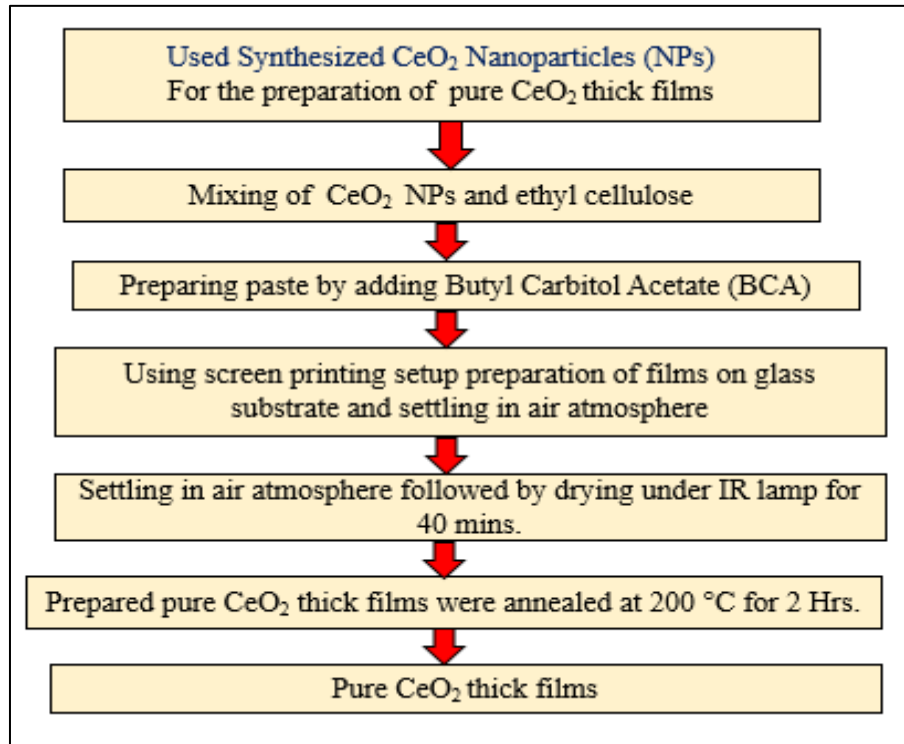


Figure 2: Steps of preparation of CeO₂ thick films using screen printing technique

2.3 Characterizations of prepared CeO₂ thick films:

2.3.1 Electrical characterizations of CeO₂ thick films:

The electrical characterization of the prepared CeO₂ thick films, key parameters such as resistivity, temperature coefficient of resistance (TCR), and activation energy in both low- and high-temperature regions were systematically investigated. These parameters are critical for understanding the semiconducting behavior and conduction mechanism of the material. The resistivity of the films was determined using Equation (1), while the TCR was calculated from the variation of resistance with temperature using Equation (2). The activation energy values corresponding to the low-temperature region (LTR) and high-temperature region (HTR) were obtained from the Arrhenius relation, as expressed in Equation (3) [16-18]. These calculations provided valuable insights into the electrical conduction and gas sensing response of the CeO₂ thick films.

$$\rho = \left(\frac{R \times b \times t}{l} \right) \Omega - m \quad (1)$$

Where, ρ = Resistivity of prepared film, R = resistance at normal temperature, b = breadth of film, t = thickness of the film, L = length of the film.

$$TCR = \frac{1}{R_o} \left(\frac{\Delta R}{\Delta T} \right) / ^\circ C \quad (2)$$

Where,

ΔR = change in resistance between temperature T_1 and T_2 ,

ΔT = temperature difference between T_1 and T_2 and R_o = room temperature resistance of the film

$$\Delta E = A e^{-E_a/kBT} \text{ eV} \quad (3)$$

Where,

ΔE = Activation energy, T = Temperature and A = Arrhenius prefactor.

2.3.2 Gas sensing analysis of CeO₂ thick films:

The gas sensing properties of the prepared CeO₂ thick films were investigated using a static gas sensing apparatus as shown in Figure 3, in which the films served as the active sensing element. During the measurements, the electrical resistance of the films was recorded at different operating temperatures and under varying concentrations of the target gas [18, 19]. The change in resistance with respect to gas exposure was used to evaluate the sensing performance of the films. The sensitivity of the CeO₂ thick films toward the test gases was calculated using Equation (4), which relates the resistance of the sensor in air and in the presence of the target gas. This analysis enabled the determination of crucial sensing parameters such as sensitivity, selectivity, response time, and recovery time, thereby providing comprehensive insights into the gas sensing behavior of the CeO₂ films [19, 20].

$$\text{Sensitivity (\%)} = \frac{R_a - R_g}{R_a} \times 100 \quad (4)$$

Where,

R_a - Film resistance in air and R_g - film resistance in a gaseous atmosphere.

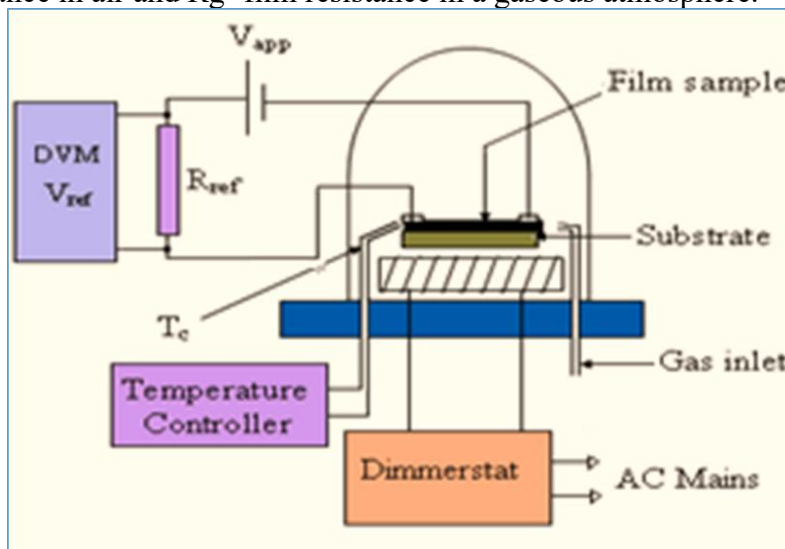


Figure 3. Schematic diagram of static gas sensing apparatus

3. RESULT AND DISCUSSION:

3.1 Electrical Characterization:

Figure 4 depicts the variation of resistance with temperature for CeO₂ thick films. It can be clearly observed that the resistance decreases continuously as the temperature increases, which is a typical characteristic of semiconducting materials. At lower temperatures, the resistance of the film is high due to limited thermal energy available for charge carriers to overcome the potential barrier [16, 17]. As the temperature increases, more charge carriers gain sufficient energy to participate in conduction, thereby reducing the resistance of the film. This negative temperature coefficient of resistance confirms the semiconducting nature of CeO₂ thick films [18].

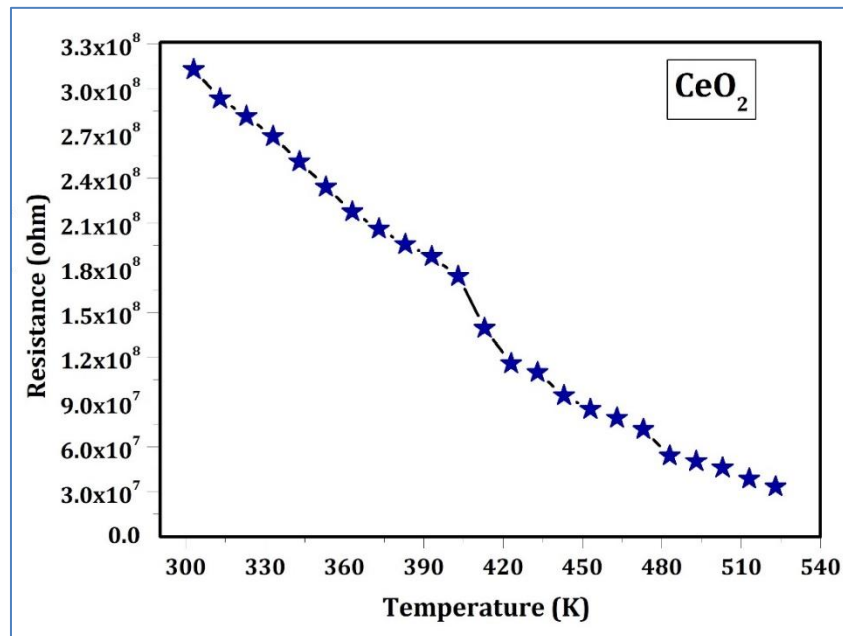


Figure 4: Resistance versus temperature of CeO₂ thick films

Figure 5 shows the Arrhenius plot of $\log(R)$ versus $1/T$ for CeO₂ thick films, which is commonly used to determine the activation energy of conduction. The linear regions in the plot correspond to different conduction mechanisms at low- and high-temperature regions (LTR and HTR, respectively) [18, 19]. The slope of the fitted straight lines in these regions provides the activation energy values, which were calculated to be 0.0546 eV in the LTR and 0.2421 eV in the HTR. The lower activation energy in the LTR suggests easier conduction at lower temperatures due to shallow trap states, whereas the higher activation energy in the HTR indicates the involvement of deeper trap states or increased grain boundary scattering [20, 21]. These results confirm the thermally activated conduction process in CeO₂ thick films and are in good agreement with semiconducting behavior observed in resistivity studies. The electrical outcomes of CeO₂ thick films are illustrate in Table 1.

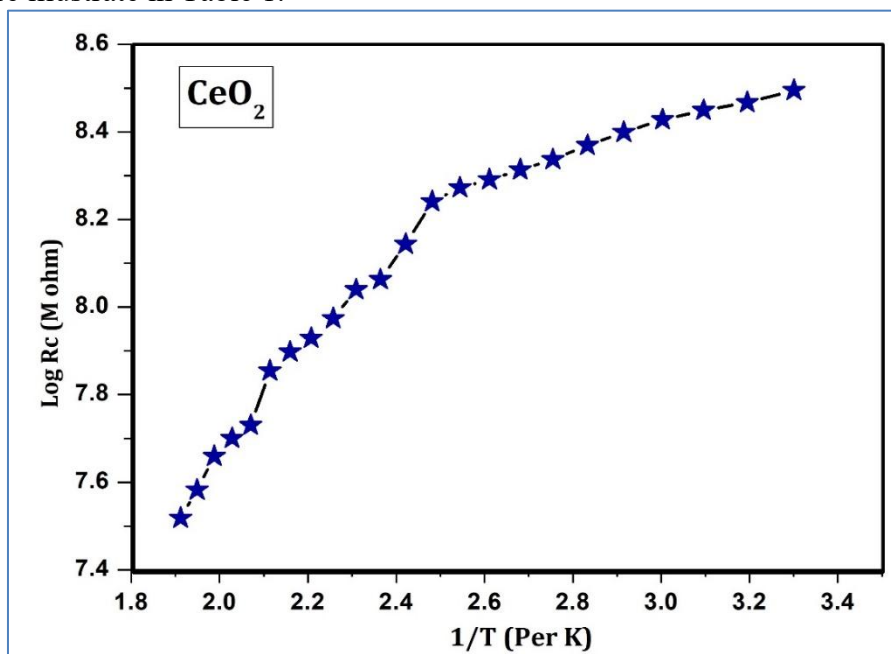


Figure 5: Arrhenius plot of CeO₂ thick films

Table-1: Electrical outcomes of CeO₂ thick films

Resistivity (Ω/m)	TCR ($^{\circ}\text{C}$)	Activation energy (eV)	
		LTR	HTR
5939.03	-0.002815	0.0546	0.2421

3.2 Gas sensing study of CeO₂ thick films

The gas sensing behavior of CeO₂ thick films was systematically studied with respect to operating temperature, selectivity, gas concentration, and response–recovery characteristics, as shown in Figure 6.

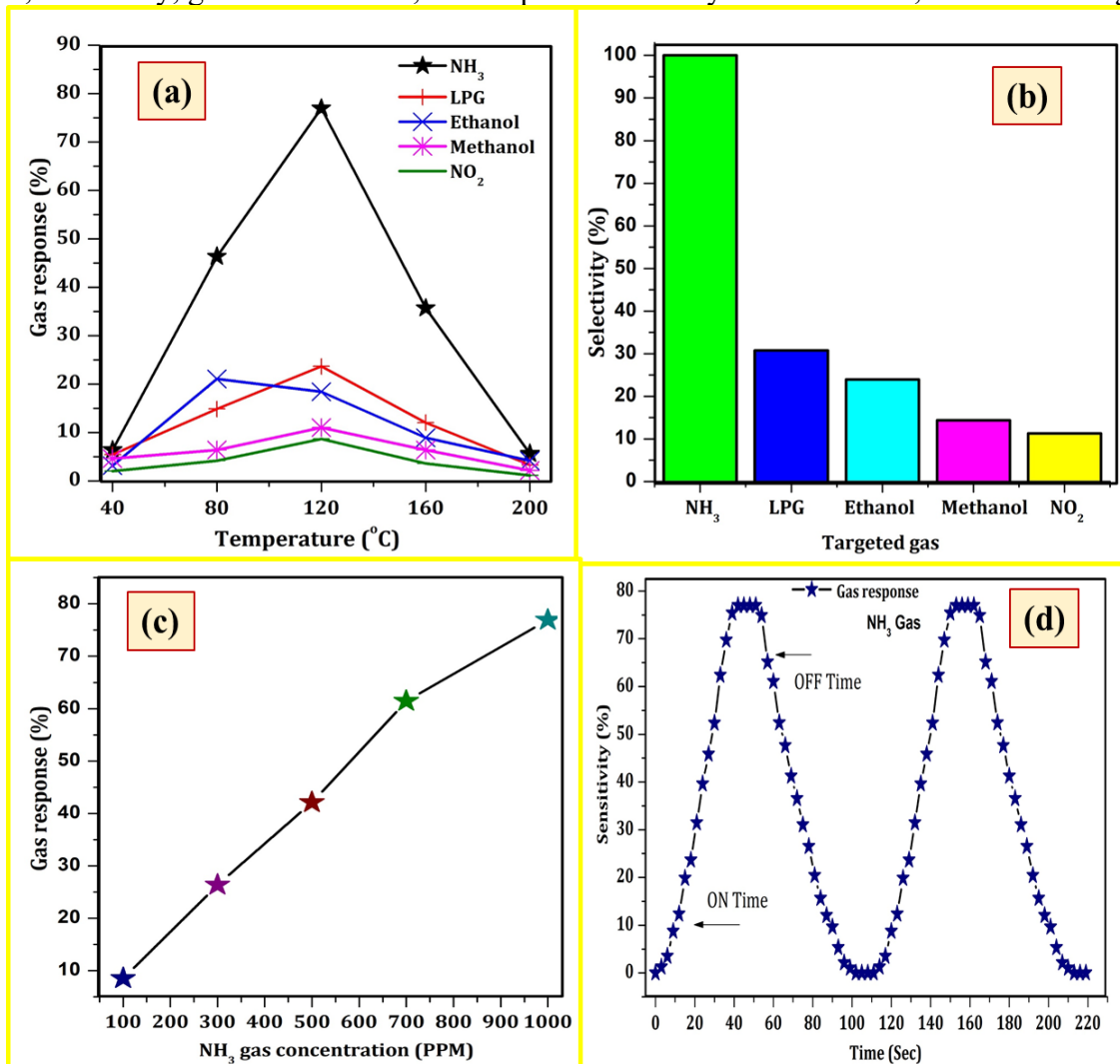


Figure 6: (a) Gas response verses operating temperature, (b) Selectivity, (c) PPM variation & (d) Response and recovery time plot of CeO₂ thick films

Figure 6 (a) illustrates the gas response of CeO₂ thick films toward different target gases such as NH₃, LPG, ethanol, methanol, and NO₂ over a temperature range of 40–200 °C. At lower operating temperatures, insufficient thermal energy restricts the surface reactions between adsorbed oxygen ions and the incoming gas molecules, leading to poor response. With an increase in temperature, surface reactions become more active due to the enhanced mobility of charge carriers and higher adsorption–desorption dynamics, thereby improving sensitivity [21, 22]. At higher temperatures (>120 °C), desorption of oxygen species occurs at a

faster rate than adsorption, reducing the availability of reactive oxygen species on the sensor surface and consequently lowering the gas response [23, 24]. The maximum sensitivity of CeO₂ thick films was found to be 76.95% toward NH₃ gas at 120 °C with a concentration of 1000 ppm, indicating that NH₃ is the most efficiently detected gas among the tested analytes. Figure 6(b) highlights the selectivity of CeO₂ thick films toward different gases. The sensor demonstrates a pronounced preference for NH₃, showing almost 100% selectivity compared to other interfering gases such as LPG, ethanol, methanol, and NO₂, which exhibit relatively low responses. High selectivity is one of the crucial requirements for practical gas sensor applications, as cross-sensitivity toward multiple gases reduces accuracy and reliability [24, 25]. The enhanced selectivity toward NH₃ can be attributed to the strong interaction between NH₃ molecules and surface-adsorbed oxygen ions on CeO₂. NH₃, being a reducing gas, reacts readily with the chemisorbed oxygen species (O⁻, O₂⁻, O²⁻) on the CeO₂ surface, releasing electrons back into the conduction band of the semiconductor, thus causing a significant decrease in resistance. This strong redox interaction enhances both the magnitude and stability of the sensing response toward NH₃ compared to other gases [26, 27]. Figure 6(c) demonstrates the variation in gas response with different concentrations of NH₃ ranging from 100 ppm to 1000 ppm at the optimum operating temperature. The response increases almost linearly with increasing concentration of NH₃, which indicates that the sensor can effectively detect a broad range of NH₃ concentrations with high sensitivity. At lower concentrations (100–300 ppm), fewer NH₃ molecules interact with the surface oxygen ions, resulting in a smaller change in resistance. As the concentration increases, a larger number of NH₃ molecules participate in the surface reaction, thereby producing a greater electron release into the conduction band and enhancing the sensing response [23, 27]. At the maximum tested concentration of 1000 ppm, the response reached 76.95%, showing the ability of CeO₂ thick films to detect even high concentrations of NH₃ with remarkable efficiency. The nearly linear dependence of sensitivity on gas concentration further confirms the suitability of CeO₂ films for quantitative gas monitoring applications. Figure 6(d) presents the dynamic response curve of CeO₂ thick films toward NH₃ gas, highlighting the response and recovery times. The response time, defined as the duration required to achieve 90% of the maximum resistance change after exposure to the target gas, was found to be approximately 12 seconds, indicating rapid adsorption and surface reaction of NH₃ molecules. The recovery time, defined as the duration required to return to 90% of the baseline resistance after removal of the gas, was found to be 54 seconds. This relatively fast recovery demonstrates that NH₃ molecules desorb quickly from the CeO₂ surface once the gas is removed, enabling the sensor to regain its original state [27, 28]. The fast response and recovery characteristics are highly desirable for real-time monitoring applications, as they ensure that the sensor can detect and reset promptly in fluctuating gas environments.

CONCLUSIONS:

The pure CeO₂ nanoparticles were successfully synthesized using the precipitation method and employed to fabricate thick films via the screen-printing technique. Electrical characterization revealed a resistivity of 5939.03 Ω-m with a negative temperature coefficient of resistance (−0.002815 /°C), confirming the semiconducting nature of the films. The activation energy values were determined as 0.0546 eV in the low-temperature region and 0.2421 eV in the high-temperature region, indicating thermally activated conduction. Gas sensing investigations demonstrated that CeO₂ thick films exhibit excellent performance toward NH₃ gas, with a maximum sensitivity of 76.95% at 120 °C for 1000 ppm concentration, along with a rapid response time of 12 s and recovery time of 54 s. The films also showed good selectivity toward NH₃ compared to other gases such as LPG, ethanol, methanol, and NO₂. These findings highlight that CeO₂ thick films, owing to their stable semiconducting behavior, oxygen vacancy-driven surface activity, and efficient redox interaction with NH₃, are promising candidates for the development of low-temperature, selective, and reliable gas sensors.

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Conflict of Interest: There are no any conflict of interest.

REFERENCES:

1. Jung, H. T. (2022). The present and future of gas sensors. *ACS sensors*, 7(4), 912-913.
2. Nikolic, M. V., Milovanovic, V., Vasiljevic, Z. Z., & Stamenkovic, Z. (2020). Semiconductor gas sensors: Materials, technology, design, and application. *Sensors*, 20(22), 6694.
3. Capone, S., Forleo, A., Francioso, L., Rella, R., Siciliano, P., Spadavecchia, J. & Taurino, A. M. (2003). Solid state gas sensors: state of the art and future activities. *Journal of optoelectronics and Advanced Materials*, 5(5), 1335-1348.
4. Dhall, S., Mehta, B. R., Tyagi, A. K., & Sood, K. (2021). A review on environmental gas sensors: Materials and technologies. *Sensors International*, 2, 100116.
5. Yaqoob, U., & Younis, M. I. (2021). Chemical gas sensors: Recent developments, challenges, and the potential of machine learning—A review. *Sensors*, 21(8), 2877.
6. Rajeshkumar, S., & Naik, P. (2018). Synthesis and biomedical applications of cerium oxide nanoparticles—a review. *Biotechnology Reports*, 17, 1-5.
7. Shcherbakov, A. B., Reukov, V. V., Yakimansky, A. V., Krasnopeeva, E. L., Ivanova, O. S., Popov, A. L., & Ivanov, V. K. (2021). CeO₂ nanoparticle-containing polymers for biomedical applications: A review. *Polymers*, 13(6), 924.
8. Putri, G. E., Arifani, N., Wendari, T. P., Syafri, E., Ilyas, R. A., Labanni, A., & Arief, S. (2024). Nanocomposites of cellulose-modified cerium oxide nanoparticles and their potential biomedical applications. *Case Studies in Chemical and Environmental Engineering*, 10, 101013.
9. Ren, G., Wang, L., & Wang, S. (2025). Innovative synthesis of CeO₂ nanoparticles for advanced chemical mechanical polishing. *Colloids and Surfaces A: Physicochemical and Engineering Aspects*, 705, 135764.
10. Gawali, S. R., Patil, V. L., Deonikar, V. G., Patil, S. S., Patil, D. R., Patil, P. S., & Pant, J. (2018). Ce doped NiO nanoparticles as selective NO₂ gas sensor. *Journal of Physics and Chemistry of Solids*, 114, 28-35.
11. Oosthuizen, D. N., Motaung, D. E., & Swart, H. C. (2020). Gas sensors based on CeO₂ nanoparticles prepared by chemical precipitation method and their temperature-dependent selectivity towards H₂S and NO₂ gases. *Applied Surface Science*, 505, 144356.
12. Shbeeb, R. T., & Mutlak, F. A. (2025). Two-Step Nanosecond Pulsed Laser Deposition-Assisted Synthesis of Gold/Cerium Oxide Nanocomposite for Enhanced Performance Photodetectors. *Plasmonics*, 1-16.
13. Farahmandjou, M., Zarinkamar, M., & Firoozabadi, T. P. (2016). Synthesis of Cerium Oxide (CeO₂) nanoparticles using simple CO-precipitation method. *Revista mexicana de fisica*, 62(5), 496-499.
14. Suresh, R., Ponnuswamy, V., & Mariappan, R. (2013). Effect of annealing temperature on the microstructural, optical and electrical properties of CeO₂ nanoparticles by chemical precipitation method. *Applied Surface Science*, 273, 457-464.
15. Liu, I. T., Hon, M. H., & Teoh, L. G. (2013). Structure and optical properties of CeO₂ nanoparticles synthesized by precipitation. *Journal of electronic materials*, 42(8), 2536-2541.
16. Tupe, U. J., Zambare, M. S., Patil, A. V., & Koli, P. B. (2020). The binary oxide NiO-CuO nanocomposite based thick film sensor for the acute detection of Hydrogen Sulphide gas vapours. *Material Science Research India*, 17(3), 260-269.

17. Suryawanshi, P. S., Patil, A. V., Padhye, G. G., & Tupe, U. J. (2024). Investigation the Influence of Calcination Temperature on Structural, Electrical and Gas Sensing Properties MnO₂ Thick Films. *Advanced Materials Research*, 1180, 67-81.
18. Magar, M. H., Adole, V. A., Patil, M. R., Waghchaure, R. H., Tupe, U. J., & Pawar, T. B. (2024). Fabrication of modified Sb₂O₃ nanospheres for the removal of hazardous malachite green organic pollutant and selective NO₂ gas sensor. *Journal of the Indian Chemical Society*, 101(11), 101396.
19. Koli, P. B., Kapadnis, K. H., Deshpande, U. G., More, B. P., & Tupe, U. J. (2020). Sol-gel fabricated transition metal Cr³⁺, Co²⁺ doped lanthanum ferric oxide (LFO-LaFeO₃) thin film sensors for the detection of toxic, flammable gases: a comparative study. *Mater Sci Res India*, 17, 70-83.
20. Mandawade, S. S., Wagh, R. V., Yewale, C. R., Qadir, K. W., Abdullah, H. Y., Alharbi, T., ... & Patil, A. V. (2025). Graphene oxide nanoparticles synthesized via hummers method and investigation of structural, electrical, and gas-sensing properties of screen-printed thick films. *Journal of the Indian Chemical Society*, 102(1), 101514.
21. Lad, U. D., Kokode, N. S., & Tupe, U. J. (2022). Study of pn Heterojunction Thin Films for Reducing Gas Sensing Application Fabricated by Thermal Evaporation Technique. *Advanced Materials Research*, 1172, 67-82.
22. Yewale, C. R., Mandawade, S. S., Qadir, K. W., Abdullah, H. Y., Wagh, R. V., Tupe, U. J., ... & Patil, A. V. (2025). Structural, Optical, and Gas Sensing Characterization of Nanostructured MgS Thin Films Prepared via Spray Pyrolysis Technique for High-Sensitivity CO₂ Detection. *Journal of the Indian Chemical Society*, 101862.
23. Rao, G. T., & Rao, D. T. (1999). Gas sensitivity of ZnO based thick film sensor to NH₃ at room temperature. *Sensors and Actuators B: Chemical*, 55(2-3), 166-169.
24. Yewale, A. K., Raulkar, K. B., Wadarkar, A. S., & Lamdhade, G. T. (2011). Application of metal oxide thick film as a NH₃ gas sensor. *Journal of Electron Devices*, 11, 544-550.
25. Takao, Y., Miyazaki, K., Shimizu, Y., & Egashira, M. (1994). High ammonia sensitive semiconductor gas sensors with double-layer structure and interface electrodes. *Journal of the Electrochemical Society*, 141(4), 1028.
26. Wang, J., Li, Z., Zhang, S., Yan, S., Cao, B., Wang, Z., & Fu, Y. (2018). Enhanced NH₃ gas-sensing performance of silica modified CeO₂ nanostructure based sensors. *Sensors and Actuators B: Chemical*, 255, 862-870.
27. Dhanawade, R. N., Pawar, N. S., Chougule, M. A., Hingangavkar, G. M., Jadhav, Y. M., Nimbalkar, T. M., ... & Patil, V. B. (2023). Highly sensitive and selective PANi-CeO₂ nanohybrid for detection of NH₃ biomarker at room temperature. *Journal of Materials Science: Materials in Electronics*, 34(9), 781.
28. Esmaeili, C., Ashtiani, S., Regmi, C., Laposa, A., Voves, J., Kroutil, J., ... & Lotfian, S. (2024). Preparation and characterisation of NH₃ gas sensor based on PANI/Fe-doped CeO₂ nanocomposite. *Heliyon*, 10(15).